

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	94	("5292677" "5234856" "5977589" "5529946" "5681773" "5837581" "5376566" "5466628" "5595927" "5751040" "5766995" "5824582" "5858833" "5929477" "5930622" "5989952" "5998253" "6013548" "6027981" "6034389" "6077745" "6087692" "6097049" "6137128" "6162681" "6172391" "4835589" "5312768" "5324680" "5326714" "5396456" "5429977" "5436187" "5442213" "5447881" "5451538" "5470776" "5488011" "5491103" "5516719" "5534458" "5545585" "5552620" "5578850" "5631185" "5652186" "5663092" "5668041" "5688713" "5710074").pn.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/16 15:36
S2	0	silicon adj substrate and STI and (gate adj dielectric or gate adj oxide) and pass adj transistor adj structure and storage adj capacitor adj structure and spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/16 15:40
S3	0	pass adj transistor adj structure and storage adj capacitor adj structure and spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/16 15:40
S4	115	pass adj transistor and storage adj capacitor and spacer	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/16 15:41
S5	17	("5198995" "5267201" "5297104" "5371705" "5377139" "5394365" "5416034" "5600598" "5694355" "5703827" "5789291" "5863819" "5963838" "5986947" "6009023" "6104055" "6352890").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/16 16:07
S6	0	("6784048").URPN.	USPAT	OR	OFF	2005/05/16 16:14
S7	16	("5198995" "5267201" "5297104" "5371705" "5377139" "5394365" "5416034" "5600598" "5694355" "5703827" "5789291" "5963838" "5986947" "6009023" "6104055" "6352890").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/16 16:16
S8	0	("6642098").URPN.	USPAT	OR	OFF	2005/05/16 16:17
S9	0	("6613615").URPN.	USPAT	OR	OFF	2005/05/16 16:17

S10	2	("5895239" "6312994").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/16 16:18
S11	1	("6573548").URPN.	USPAT	OR	OFF	2005/05/16 16:19
S12	17	("5198995" "5267201" "5297104" "5371705" "5377139" "5394365" "5416034" "5449636" "5600598" "5694355" "5703827" "5789291" "5963838" "5986947" "6009023" "6104055" "6352890").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/05/16 16:20
S13	1782	silicon adj substrate and STI and (gate adj dielectric or gate adj oxide)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/16 17:37
S14	64	silicon adj substrate and STI and (gate adj dielectric or gate adj oxide) and pass adj transistor	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/16 17:37
S15	7	silicon adj substrate and STI and (gate adj dielectric or gate adj oxide) and pass adj transistor and storage adj transistor	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/16 17:38